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# UTILITY PATENT APPLICATION TRANSMITTAL

☒ Only for new nonprovisional applications  
under 37 CFR 1.53(b))

Attorney Docket No.	990659	Total Pages	
First Named Inventor or Application Identifier			
Taisuke HIROOKA and Hidetaka SAKUMICHI			
Express Mail Label No.			

Check Box, if applicable ☐ Duplicate

APPLICATION ELEMENTS FOR:  
CLEANING AND HANDLING METHODS OF  
ELECTRONIC COMPONENT AND CLEANING  
APPARATUS THEREOF

ADDRESS TO: Assistant Commissioner for Patents  
BOX PATENT APPLICATIONS  
Washington, D.C. 20231

1. ☒ Fee Transmittal Form (Incorporated within this form)  
(Submit an original and a duplicate for fee processing)
2. ☒ Specification Total Pages [16]
3. ☒ Drawing(s) (35 USC 113) Total Sheets [8]
4. ☒ Oath or Declaration Total Pages [2]
  - a. ☒ Newly executed (original)
  - b. ☐ Copy from prior application (37 CFR 1.63(d)  
(for continuation/divisional with Box 17 completed).
  - i. ☐ Deletion of Inventor(s)  
Signed statement attached deleting inventor(s) named in prior application,  
see 37 CFR 1.63(d)(2) and 1.33(b).
5. ☐ Incorporation by reference (useable if box 4b is checked)  
The entire disclosure of the prior application, from which a copy of the oath or declaration is supplied under  
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7. ☐ Nucleotide and/or Amino Acid Sequence Submission (if applicable, all necessary)
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## ACCOMPANYING APPLICATION PARTS

8. ☒ Assignment Papers (cover sheet and document(s))
9. ☐ 37 CFR 3.73(b) Statement (when there is an assignee) ☒ Power of Attorney

# UTILITY PATENT APPLICATION TRANSMITTAL

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**PAGE 2 OF 3**

10. ☐ English translation Document (if applicable)
11. ☐ Information Disclosure Statement ☐ Copies of IDS Citations
12. ☐ Preliminary Amendment
13. ☒ Return Receipt Postcard (MPEP 503)
14. ☐ Small Entity Statement(s) ☐ Statement filed in prior application  
Status still proper and desired.
15. ☒ Claim for Convention Priority ☐ [2] Certified copies of Priority Document(s)
- a. Priority of \_\_\_\_\_ application no. \_\_\_\_\_ filed on \_\_\_\_\_ is claimed under 35 USC 119.  
The certified copies/copy have/has been filed in prior application Serial No. \_\_\_\_\_.  
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16. ☐ Other \_\_\_\_\_
17. If a CONTINUING APPLICATION, check appropriate box and supply the requisite information:  
☐ Continuation ☐ Division ☐ Continuation-in-part (CIP) of prior application no. \_\_\_\_/\_\_\_\_

FEE TRANSMITTAL	Number Filed	Number Extra	Rate	Basic Fee
The filing fee is calculated below				\$760.00
Total Claims	27 - 20	7	x \$18.00	126.00
Independent Claims	5 - 3	2	x \$78.00	156.00
Multiple Dependent Claims			\$260.00	260.00
Basic Filing Fee				1302.00
Reduction by 1/2 for small entity				
Fee for recording enclosed Assignment			\$40.00	40.00
TOTAL				\$1342.00

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APPLICATION TRANSMITTAL**

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**Taisuke HIROOKA and Hidetaka SAKUMICHI**

**PAGE 3 OF 3**

☒ [XX] A check in the amount of \$1,342.00 is enclosed to cover the filing fee of \$1,302.00 and the assignment recordation fee of \$40.00.

☐ [ ] Please charge our Deposit Account No. **01-2340** in the total amount of \_\_\_\_\_ to cover the filing fee and the \_\_\_\_\_ assignment recordation fee. A duplicate of this sheet is attached.

☒ [XX] The Commissioner is hereby authorized to charge payment for any additional filing fees required under 37 CFR 1.16 or credit any overpayment to Deposit Account No. **01-2340**. A duplicate of this sheet is attached.

**18. CORRESPONDENCE ADDRESS**

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**SUBMITTED BY**

Typed or Printed Name **Stephen G. Adrian**

Reg. No. 32,878

Signature 

Date: June 22, 1999

SGA/yap

# CLEANING AND HANDLING METHODS OF ELECTRONIC COMPONENT AND CLEANING APPARATUS THEREOF

## TECHNICAL FIELD

The present invention relates to cleaning and handling methods of an electronic component and a cleaning apparatus thereof, and more particularly, to cleaning and handling methods of an electronic component suitable for cleaning of a ceramic wafer such as a wafer made of, e.g., alumina titanium carbide, and to a cleaning apparatus therefor.

## BACKGROUND TECHNIQUE

Conventionally, as a cleaning method of an electronic component of this type, there is a known cleaning method for cleaning an object to be cleaned (which will be referred to as an object to be cleaned, hereinafter) using a sponge member while supplying cleaning water to the object to be cleaned.

In the case of such a conventional cleaning method, a considerably high cleaning degree is obtained by both cleaning with the cleaning water and wiping operation of the object to be cleaned with the sponge member.

However, when the object to be cleaned is wiped with the sponge member, the object to be cleaned is adversely charged with electricity, and there are problems that even if the cleaning operation is repeated, the certain amount of dust is remained, and the object to be cleaned is soiled with the dust adhered to the sponge member.

Thereupon, it is an object to provide cleaning and handling methods of an electronic component and a cleaning apparatus therefor capable of achieving the cleaning degree higher than that of the conventional cleaning method of the electronic component.

## DISCLOSURE OF THE INVENTION

The present inventors wholeheartedly studied to solve the above problems and as a result, they found that it is possible to clean an electronic component extremely excellently by using

cleaning water having the resistivity value of  $10\text{M}\Omega$  or less, by separating the sponge member from the object to be cleaned during cleaning to clean the sponge member with the cleaning water having the resistivity value of  $10\text{M}\Omega$  or less, and by soaking the object to be cleaned in the cleaning water having the resistivity value of  $10\text{M}\Omega$  or less before cleaning.

The present invention has been achieved based on these facts, and according to a first aspect of the present invention, there is provided a cleaning method of an electronic component wherein an object to be cleaned is cleaned using a sponge member while supplying, to the object to be cleaned, cleaning water having the resistivity value of  $10\text{M}\Omega$  or less.

According to a second aspect, in the first aspect, the resistivity value of the cleaning water is adjusted to  $5\text{M}\Omega$  or less by including carbon dioxide gas in the cleaning water.

According to a third aspect, in the first aspect, the sponge member is separated from the object to be cleaned during cleaning, and the cleaning water is supplied also to the separated sponge member.

According to a fourth aspect, in the second aspect, the sponge member is separated from the object to be cleaned during cleaning, and the cleaning water is supplied also to the separated sponge member.

According to a fifth aspect, in the first aspect, the object to be cleaned is a ceramic wafer.

According to a sixth aspect, in the second aspect, the object to be cleaned is a ceramic wafer.

According to a seventh aspect, in the third aspect, the object to be cleaned is a ceramic wafer.

According to an eighth aspect, in the fourth aspect, the object to be cleaned is a ceramic wafer.

According to a ninth aspect, there is provided a cleaning method of an electronic component wherein an object to be cleaned is soaked in cleaning water having the resistivity value of  $10\text{M}\Omega$  or less before cleaning.

According to a tenth aspect, in any one of the first to

ninth aspects, the object to be cleaned is soaked in the cleaning water having the resistivity value of  $10M\Omega$  or less before cleaning.

According to an eleventh aspect, there is provided a handling method of an electronic component wherein a substrate which is an object to be cleaned is placed on a substrate holding piece of a substrate rack, and when the substrate is cleaned and then the substrate is placed on another substrate holding piece of another substrate rack, a dummy substrate is located on a film formed surface of the substrate.

According to a twelfth aspect, there is provided a handling method of an electronic component wherein when a substrate which is an object to be cleaned is cleaned and then is preserved in a state in which the substrate is placed on a substrate holding piece of a substrate rack, the substrate rack is inclined so that a film formed surface side does not contact with the substrate holding piece of the substrate rack.

According to a thirteenth aspect, in the eleventh aspect, when a substrate which is an object to be cleaned is cleaned and then is preserved in a state in which the substrate is placed on a substrate holding piece of a substrate rack, the substrate rack is inclined so that a film formed surface side does not contact with the substrate holding piece of the substrate rack.

According to a fourteenth aspect, there is provided a cleaning apparatus of an electronic component comprising: means for supplying cleaning water to an object to be cleaned, a sponge member for contacting with the object to be cleaned to clean a surface thereof, means for moving the object to be cleaned and the sponge member relative to each other, and means for adjusting the resistivity value of the cleaning water to  $10M\Omega$  or less.

According to a fifteenth aspect, in the fourteenth aspect, the apparatus further comprises a soaking portion for soaking the object to be cleaned before being cleaned into the cleaning water having the resistivity value of  $10M\Omega$  or less.

According to a sixteenth aspect, in the fourteenth aspect,

the apparatus further comprises means for supplying carbon dioxide gas for adjusting the resistivity value of the cleaning water to  $5M\Omega$  or less.

According to a seventeenth aspect, in the fifteenth aspect, the apparatus further comprises means for supplying carbon dioxide gas for adjusting the resistivity value of the cleaning water to  $5M\Omega$  or less.

According to an eighteenth aspect, in the fourteenth aspect, the apparatus further comprises means for supplying the cleaning water also to the sponge member which is separated from the object to be cleaned during cleaning.

According to a nineteenth aspect, in the fifteenth aspect, the apparatus further comprises means for supplying the cleaning water also to the sponge member which is separated from the object to be cleaned during cleaning.

According to the present invention, in the cleaning method of an electronic component for cleaning an object to be cleaned using a sponge member while supplying the cleaning water to the object to be cleaned, it is possible to achieve the rapid and excellent cleaning by the extremely simple means, i.e., by adjusting the resistivity of the cleaning water, and this effect could not be obtained by the conventional cleaning method of electronic component in which the object to be cleaned is cleaned with cleaning water and wiped.

#### BRIEF DESCRIPTION OF DRAWINGS

Fig.1 is an explanatory diagram of an embodiment of a cleaning apparatus of an electronic component;

Fig.2 is a plan view of a stage of the cleaning apparatus;

Fig.3 is a graph of characteristics showing the cleaning effect by a cleaning method of the electronic component of the present invention;

Fig.4 is a graph showing the relation between resistivity value of cleaning water and the cleaning degree of an object to be cleaned by the cleaning method of the electronic component of the present invention;

Fig.5 is a perspective view of a cleaning apparatus of an electronic component according to another embodiment of the present invention;

Fig.6 is a front view of a substrate rack accommodating a substrate before it is cleaned;

Fig.7 is a front view of a substrate rack accommodating a substrate after it is cleaned;

Fig.8 is an explanatory diagram showing a keeping state of the substrate rack; and

Fig.9 is a graph of characteristics for explaining the soil preventing effect using a dummy substrate.

#### BEST MODE FOR CARRYING OUT THE INVENTION

Embodiments of the present invention will be explained based on the drawings below.

Figs.1 and 2 show an embodiment of a cleaning apparatus of an electronic component of the present invention. In the drawings, the reference number 1 represents a ring-like stage fixed on an upper end of a driving shaft 2 which is rotated through a driving mechanism (not shown). As shown in Fig.2, the ring-like stage includes a ring-like member 1a, and supporting projections 1b disposed along an inner periphery of the ring-like member at a distance from one another. A object to be cleaned 20 such as a wafer made of alumina titanium carbide is placed on the supporting projections 1b so that both front and back surfaces of the object to be cleaned 20 can simultaneously be cleaned utilizing central space 1c of the stage 1.

In Fig.1, the reference number 3 represents a cleaning water supply nozzle for supplying cleaning water 30 to the object to be cleaned 20. The nozzle 3 is connected to a superpure water tank 5 through a supply pipe 4. A desired amount of carbon dioxide gas is supplied to the superpure water tank 5 from a carbon dioxide gas cylinder 7 connected to the latter through a connection pipe 6, and the cleaning water 30 is supplied to the object to be cleaned 20 from the cleaning water



supply nozzle 3. The resistivity of cleaning water 30 can be adjusted to  $10M\Omega$  or less.

In Fig.1, the reference numbers 8 represent a pair of sponge members each comprising polyvinyl alcohol sponge (Bellclean by trademark of Kanebou Corp.). Each of the sponge member 8 are capable of rotating through a driving mechanism (not shown), and is brought into contact with a surface of the object to be cleaned so that dust existing on the object to be cleaned 20 is wiped away with the projections 8a formed on the surface of the sponge member 8.

The pair of sponge members 8 are connected to a fulcrum 9 through arm members 10. The sponge members 8 are arranged such that the members 8 sandwich and simultaneously clean both the front and back surfaces of the object to be cleaned 20 by the swinging movement of the arm members 10, and such that the sponge members 8 simultaneously separate from the object to be cleaned.

In a position of each of the sponge members 8 separated from the object to be cleaned 20, a cleaning water supply nozzle 13 is closely disposed. The cleaning water supply nozzle 13 is connected to the superpure water tank 5 through a supply pipe 14. In the separated position of the sponge member 8, cleaning water 30 whose resistivity is adjusted to be  $10M\Omega$  or less is supplied. In Fig.1, the reference number 31 represents a saucer of the cleaning water. Although the saucer 31 merely receives the cleaning water 30 supplied from the cleaning water supply nozzle 13 in the present embodiment, the saucer 31 may be filled with cleaning water 30 and the sponge member 8 may be soaked therein.

A cleaning method using the cleaning apparatus for the electronic component will be explained next.

First, the object to be cleaned 20 is place on a predetermined position of the stage, the stage 1 is rotated and the cleaning water 30 is supplied to the object to be cleaned 20. It is preferable that the cleaning water 30 is supplied such that the cleaning water 30 sufficiently widespread on both

the front and back surfaces of the object to be cleaned 20, and that the supply of the cleaning water 30 is continued until the cleaning operation of the object to be cleaned 20 is completed.

Next, the sponge members 8 which are rotating are brought close to positions to contact with the front and back surfaces of the object to be cleaned 20 to which the cleaning water 30 is supplied, so as to wipe off the dust on the object to be cleaned 20 such that the projections 8a provided on the surfaces of the sponge members 8 wipe both the front and back surfaces of the object to be cleaned 20.

At that time, since the resistivity of the cleaning water 20 is adjusted to be  $10M\Omega$  or less, the object to be cleaned 20 is not charged with electricity by the contact with the sponge members 8 and therefore, dust should not be remained on the object to be cleaned 20.

When appropriate time during the cleaning, the sponge members 8 are separated from the object to be cleaned 20, and in the separated positions, the cleaning water 30 whose resistivity is adjusted to be  $10M\Omega$  or less is supplied to the sponge members 8 from the cleaning water supply nozzles 13, thereby removing the dust adhered to the sponge members 8.

Since the sponge members are appropriately cleaned with the cleaning water 30 whose resistivity is adjusted to be  $10M\Omega$  or less in this manner, it is possible to keep clean the sponge members 8 which contact with the object to be cleaned 20 to wipe the dust existing on the surfaces thereof during the cleaning operation.

Since the object to be cleaned is cleaned using the cleaning water 30 whose resistivity is adjusted to be  $10M\Omega$  or less in this manner, the object to be cleaned should not be charged with electricity even though the sponge members 8 are used, it is unnecessary to repeat the cleaning operation many times, and it is possible to clean the object to be cleaned to a high cleaning degree.

Although the carbon dioxide gas is supplied to the superpure water from the carbon dioxide gas cylinder 7 as the

means for adjusting the resistivity of the cleaning water comprising the superpure water in the present embodiment, the adjusting means of the resistivity of the cleaning water is not limited to this. For example, if the object to be cleaned is not easily influenced by alkali such as zirconia, alkali ion using ammonia may be added. Further, if the object to be cleaned is not easily influenced by acid such as alumina, it is possible to add sulfur oxide or nitrogen oxide.

However, when the object to be cleaned is weak in alkali such as alumina titanium carbide wafer, and when an outbreak and processing of powder generated by adding the sulfur oxide or nitrogen oxide are not appropriate, it is most preferable to add carbon dioxide as in the present embodiment.

Fig.5 shows another embodiment of a cleaning apparatus of an electronic component of the present invention.

Elements similar to those in the previous embodiment are represented with the same reference numbers, and their detailed explanations will be omitted.

In the present embodiment, a soak tank 41 into which cleaning water whose resistivity is adjusted to be  $10M\Omega$  or less is supplied is provided in a left end of an apparatus body 40 so that the object to be cleaned 20 which is a substrate can be soaked in the cleaning water before the cleaning operation. At that time, the resistivity of the cleaning water supplied into the soak tank 41 is adjusted to  $5M\Omega$  or less by supplying carbon dioxide gas from a carbon dioxide gas cylinder (not shown).

The reference number 42 represents substrate racks each having a plurality of, ten in the illustrated embodiment, substrate holding pieces 42a. A plurality of substrates 20 can be placed on the substrate holding pieces 42a and accommodated. The substrates 20 before being cleaned (which will be referred to as pre-cleaning substrate) are accommodated on the left side substrate rack 42 in Fig.5, and the substrates 20 after being cleaned (which will be referred to as post-cleaning substrate) are accommodated on the right side substrate rack 42 in Fig.5.

The reference number 43 represents a substrate take-out arm for taking out the pre-cleaning substrate 20 from the substrate rack 42 soaked in the soak tank 41 and transferring the same onto the stage 1. The reference number 44 represents a substrate transfer arm for transferring the post-cleaning substrate 20 to a next spin dryer 45. The reference number 46 represents a substrate accommodation arm for taking out the dried substrate 20 from the spin dryer 45 and accommodating the same on the substrate rack 42.

A cleaning method using the cleaning apparatus for the electronic component will be explained next.

First, a dummy substrate 20d is accommodated in the lowermost position of the substrate rack 42, the pre-cleaning substrate 20 are accommodated above the dummy substrate 20d such that a film formed surface of each of the substrates 20 is directed upward, and the substrate rack 42 is soaked in the soak tank 41 to prepare for the next cleaning step.

Next, the dummy substrate 20d and then the other substrates 20 are sequentially taken out from the lowermost side of the substrate rack 42 by the substrate take-out arm 43 and are transferred onto the stage 1. Although the detailed explanation is not repeated, each of the substrates 20 is cleaned by the sponge members 8 which supplying the cleaning water having the resistivity of  $10M\Omega$  or less as in the previous embodiment.

By soaking the substrate 20 in the soak tank 41 filled with the cleaning water having the resistivity of  $10M\Omega$  or less before the cleaning operation using the sponge member 8 in this manner, dust is more reliably prevented from adhering to the substrate 20 which is the object to be cleaned by static electricity, and a higher cleaning degree is achieved.

Next, the cleaned substrate 20 is transferred from the stage 1 to the spin dryer 45 by the substrate transfer arm 44 to dry the substrate 20 by the spin dryer 45.

Thereafter, the substrates 20 are sequentially transferred from the spin dryer 45 to the substrate rack 42 and

accommodated therein from its uppermost position.

By repeating such cleaning step, drying step and accommodating step, the dummy substrate 20d which was located at the lowermost position in the substrate rack 42 accommodating the pre-cleaning substrates as shown in Fig.6 is now accommodated at the uppermost position in the substrate rack 42 accommodating the dried substrates 20 as shown in Fig.7. This dummy substrate 20d prevents the film formed surfaces of the cleaned substrates 20 sequentially accommodated below the dummy substrate 20 from being soiled.

Further, according to the present embodiment, the substrate rack 42 for accommodating the cleaned and dried substrates 20 is inclined and accommodated in a keeping box 50 as shown in Fig.8. Therefore, the substrates 20 are kept such that their film formed surfaces do not contact with the substrate holding pieces 42a.

Ten substrates (including dummy substrate) accommodated in the keeping box 50 and then the keeping box 50 is placed outside a clean room within a plant, and a degree of soil was measured. Fig.9 shows results of the measurement. As can be seen from Fig.9, it was confirmed that only the dummy substrate was soiled, and the soil preventing effect using the dummy substrate was great.

The degree of soil was measured and evaluated using alumina titanium carbide wafer having a diameter of four inches and a thickness of 2 mm, and Surfscan made by Tencor Corp. (laser type particle counter having resolving power of  $0.5\mu\text{m}$  or more).

A concrete example using the cleaning apparatus of the electronic component described in the above embodiments will be explained next.

In the present example, alumina titanium carbide wafer having a diameter of four inches was used as the object to be cleaned.

As the cleaning water, carbon dioxide gas was supplied to superpure water and substantially saturated, and the resistivity was adjusted to  $0.3\text{M}\Omega$ .

In the cleaning process, the alumina titanium carbide wafer having a diameter of four inches was used and the number of particles on the wafer was previously measured, time of one brushing cleaning step was set to 30 seconds, and spin dry was carried out per one brushing cleaning process. The number of particles on the wafer was measured at each cleaning step. Such cleaning step and measurement were repeated.

The number of particles on the wafer was measured using Surfscan made by Tencor Corp. (laser type particle counter having resolving power of  $0.5\mu\text{m}$  or more).

As a comparative example, superpure water (resistivity of  $17\text{M}\Omega$ ) was used as the cleaning water and the alumina titanium carbide wafer having a diameter of four inches was cleaned in the same manner as that of the example, and the measurement was repeated.

Next, the number of particles remained on a surface of each of the alumina titanium carbide wafers of the present example and the comparative example was measured, and its result is shown in Fig.3 as elimination rate.

As shown in Fig.3, in the case of the present example, a high cleaning degree as high as substantially 100% elimination rate could be achieved by three cleaning cycles. Whereas, in the case of the comparative example, 100% elimination rate could not be achieved even though the cleaning cycle was repeated more than five times, and even if the cleaning cycle was further repeated, the elimination rate was not enhanced, and the higher cleaning was not possible.

Next, the value of the resistivity of the cleaning water and a cleaning degree of the object to be cleaned were measured.

An alumina titanium carbide wafer having a diameter of four inches as in the previous example was used as the object to be cleaned. As the cleaning water, carbon dioxide gas was supplied to superpure water while adjusting its flow rate, and the resistivity was adjusted to  $0.1$  to  $17\text{M}\Omega$ . Other conditions were the same as those of the previous example, and the cleaning step was carried out once and then, the number of particles on

the wafer was measured, and its result is shown in Fig.4 as elimination rate.

As shown in Fig.4, it was confirmed that the elimination rate of the particles is extremely increased as the resistivity of the cleaning water becomes equal to 10M or less, especially equal to 5m $\Omega$  or less.

WHAT IS CLAIMED IS:

1. A cleaning method of an electronic component wherein an object to be cleaned is cleaned using a sponge member while supplying, to said object to be cleaned, cleaning water having the resistivity value of  $10M\Omega$  or less.
2. A cleaning method of an electronic component according to claim 1, wherein the resistivity value of said cleaning water is adjusted to  $5M\Omega$  or less by including carbon dioxide gas in said cleaning water.
3. A cleaning method of an electronic component according to claim 1, wherein said sponge member is separated from said object to be cleaned during cleaning, and said cleaning water is supplied also to said separated sponge member.
4. A cleaning method of an electronic component according to claim 2, wherein said sponge member is separated from said object to be cleaned during cleaning, and said cleaning water is supplied also to said separated sponge member.
5. A cleaning method of an electronic component according to claim 1, wherein said object to be cleaned is a ceramic wafer.
6. A cleaning method of an electronic component according to claim 2, wherein said object to be cleaned is a ceramic wafer.
7. A cleaning method of an electronic component according to claim 3, wherein said object to be cleaned is a ceramic wafer.
8. A cleaning method of an electronic component according to claim 4, wherein said object to be cleaned is a ceramic wafer.
9. A cleaning method of an electronic component wherein an object to be cleaned is soaked in cleaning water having the resistivity value of  $10M\Omega$  or less before cleaning.
10. A cleaning method of an electronic component according to any one of claims 1 to 9, wherein said object to be cleaned is soaked in said cleaning water having the resistivity value of  $10M\Omega$  or less before cleaning.
11. A handling method of an electronic component wherein a substrate which is an object to be cleaned is placed on a substrate holding piece of a substrate rack, and when said substrate is cleaned and then said substrate is placed on



another substrate holding piece of another substrate rack, a dummy substrate is located on a film formed surface of said substrate.

12. A handling method of an electronic component wherein when a substrate which is an object to be cleaned is cleaned and then is preserved in a state in which said substrate is placed on a substrate holding piece of a substrate rack, said substrate rack is inclined so that a film formed surface side does not contact with said substrate holding piece of said substrate rack.

13. A cleaning method of an electronic component according to claim 11, wherein when a substrate which is an object to be cleaned is cleaned and then is preserved in a state in which said substrate is placed on a substrate holding piece of a substrate rack, said substrate rack is inclined so that a film formed surface side does not contact with said substrate holding piece of said substrate rack.

14. A cleaning apparatus of an electronic component comprising: means for supplying cleaning water to an object to be cleaned, a sponge member for contacting with said object to be cleaned to clean a surface thereof, means for moving said object to be cleaned and said sponge member relative to each other, and means for adjusting the resistivity value of said cleaning water to  $10M\Omega$  or less.

15. A cleaning apparatus of an electronic component according to claim 14, further comprising a soaking portion for soaking said object to be cleaned before being cleaned into said cleaning water having the resistivity value of  $10M\Omega$  or less.

16. A cleaning apparatus of an electronic component according to claim 14, further comprising means for supplying carbon dioxide gas for adjusting the resistivity value of said cleaning water to  $5M\Omega$  or less.

17. A cleaning apparatus of an electronic component according to claim 15, further comprising means for supplying carbon dioxide gas for adjusting the resistivity value of said cleaning water to  $5M\Omega$  or less.

18. A cleaning apparatus of an electronic component according to claim 14, further comprising means for supplying said cleaning water also to said sponge member which is separated from said object to be cleaned during cleaning.

19. A cleaning apparatus of an electronic component according to claim 15, further comprising means for supplying said cleaning water also to said sponge member which is separated from said object to be cleaned during cleaning.

#### ABSTRACT OF DISCLOSURE

A cleaning apparatus of an electronic component of the present invention comprises: means for supplying cleaning water to an object to be cleaned such as alumina titanium carbide wafer, a sponge member for contacting with the object to be cleaned to clean a surface thereof, means for moving the object to be cleaned and the sponge member relative to each other, and means for adjusting the resistivity value of the cleaning water to  $10M\Omega$  or less. Using this apparatus, the object to be cleaned is cleaned using the sponge member while supplying, to the object to be cleaned, cleaning water having the resistivity value of  $10M\Omega$  or less. In this case, the cleaning degree is enhanced by soaking the object to be cleaned in the water having the resistivity value of  $10M\Omega$  or less before cleaning, and by using a dummy substrate.

FIG. 1

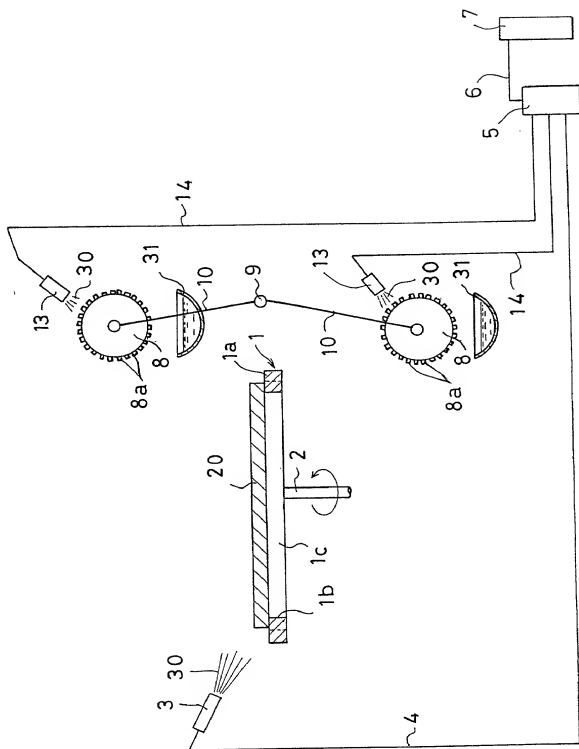


FIG. 2

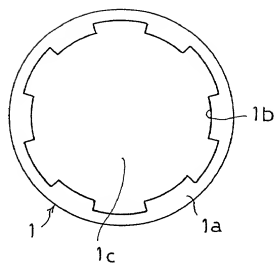


FIG. 3

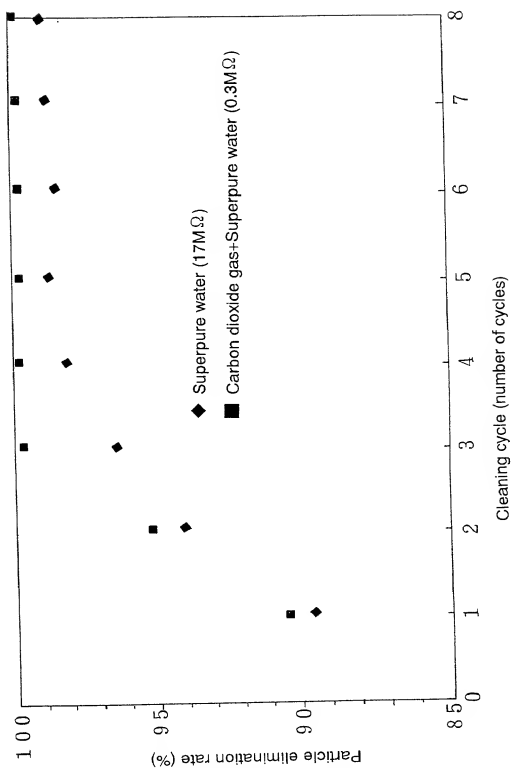
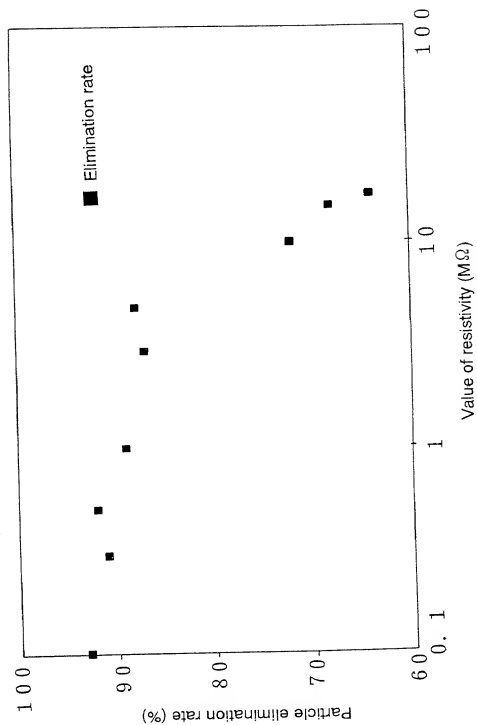


FIG. 4



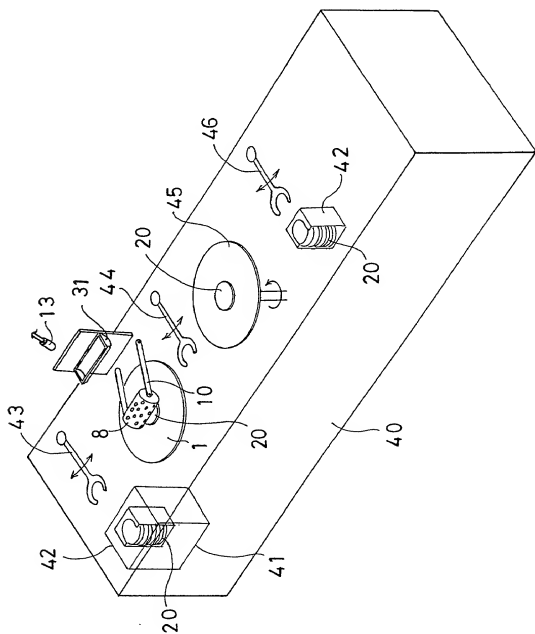
[illegible]



FIG. 6

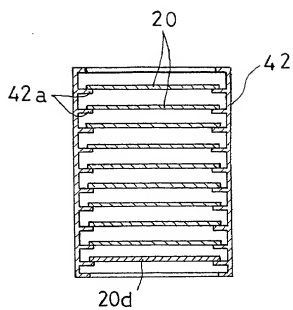


FIG. 7

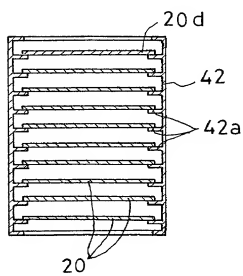


FIG. 8

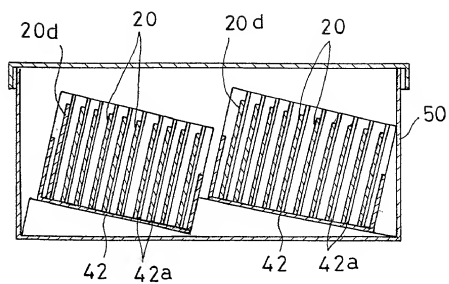
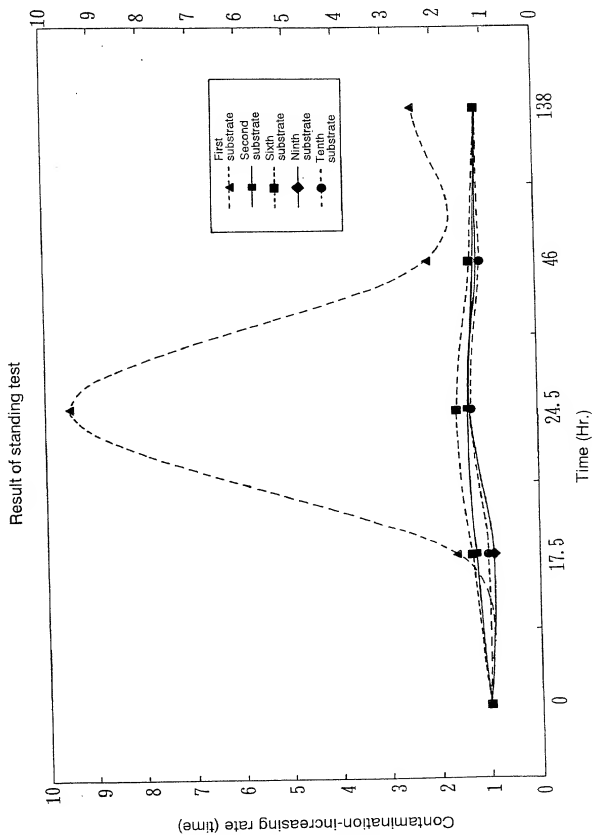


FIG. 9



**Declaration For U.S. Patent Application**

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention **entitled**  
(Insert Title) CLEANING AND HANDLING METHODS OF ELECTRONIC  
COMPONENT AND CLEANING APPARATUS THEREOF

the specification of which is attached hereto unless the following is checked:

☐ was filed on \_\_\_\_\_ as United States Application Number or PCT International  
Application Number \_\_\_\_\_ and was amended on \_\_\_\_\_  
(if applicable).

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claim(s), as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, § 119 (a) - (d) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

(List prior  
foreign  
applications.  
See note A  
on back of  
this page)

No. 10-193758  
(Number)  
No. 10-343551  
(Number)  
(Number)

Japan  
(Country)  
Japan  
(Country)  
(Country)

24/06/1998  
(Day/Month/Year Filed)  
17/11/1998  
(Day/Month/Year Filed)  
(Day/Month/Year Filed)

Priority Claimed  
☒ Yes ☐ No  
☒ Yes ☐ No  
☒ Yes ☐ No  
☒ Yes ☐ No

(See note B on back of this page)

☐ See attached list for additional prior foreign applications

I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below.

_____	_____
(Application Number)	(Filing Date)
_____	_____
(Application Number)	(Filing Date)

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of the application:

(List Prior U.S. Applications)	_____	_____	_____
	(Application Serial Number)	(Filing Date)	(Status) (patented, pending, abandoned)
	_____	_____	_____
	(Application Serial Number)	(Filing Date)	(Status) (patented, pending, abandoned)

I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith:

James E. Armstrong, III, Reg. No. 18,366; William F. Westerman, Reg. No. 29,988; Ken-Ichi Hattori, Reg. No. 32,861; Le-Nhung McLeland, Reg. No. 31,541; Ronald F. Naughton, Reg. No. 24,616; John R. Pegan, Reg. No. 18,069; William G. Kratz, Jr., Reg. No. 22,631; Albert Tockman, Reg. No. 19,722; Mel R. Quintos, Reg. No. 31,898; Donald W. Hanson, Reg. No. 27,133; Stephen G. Adrian, Reg. No. 32,878; William L. Brooks, Reg. No. 34,129; John F. Carney, Reg. No. 20,276; Edward F. Welsh, Reg. No. 22,455; Patrick D. Muir, Reg. No. 37,403; Gay A. Spahn, Reg. No. 34,978; and John P. Kong, Reg. No. 40,054.

Please direct all communications to the following address:

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Title 18 of the United States Code, § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole or first inventor (given name, family name) Taisuke HIROOKA

(See note  
C above)

Inventor's Signature Taisuke Hirooka Date May 12, 1999

Residence Hyogo Citizenship Japanese

Post Office Address 1-2-19, Kunitamadori, Nada-ku, Kobe-shi, Hyogo Japan

Full name of second inventor (given name, family name) Hidetaka SAKUMICHI

Inventor's Signature Hidetaka SAKUMICHI Date May 12, 1999

Residence Hyogo Citizenship Japanese

Post Office Address 8-1-1, Sakuragaoka, Itami-shi, Hyogo Japan

Full name of third inventor (given name, family name) \_\_\_\_\_

Inventor's Signature \_\_\_\_\_ Date \_\_\_\_\_

Residence \_\_\_\_\_ Citizenship \_\_\_\_\_

Post Office Address \_\_\_\_\_

Full name of fourth inventor (given name, family name) \_\_\_\_\_

Inventor's Signature \_\_\_\_\_ Date \_\_\_\_\_

Residence \_\_\_\_\_ Citizenship \_\_\_\_\_

Post Office Address \_\_\_\_\_

Full name of fifth inventor (given name, family name) \_\_\_\_\_

Inventor's Signature \_\_\_\_\_ Date \_\_\_\_\_

Residence \_\_\_\_\_ Citizenship \_\_\_\_\_

Post Office Address \_\_\_\_\_

Full name of sixth inventor (given name, family name) \_\_\_\_\_

Inventor's Signature \_\_\_\_\_ Date \_\_\_\_\_

Residence \_\_\_\_\_ Citizenship \_\_\_\_\_

Post Office Address \_\_\_\_\_

Full name of seventh inventor (given name, family name) \_\_\_\_\_

Inventor's Signature \_\_\_\_\_ Date \_\_\_\_\_

Residence \_\_\_\_\_ Citizenship \_\_\_\_\_

Post Office Address \_\_\_\_\_

Full name of eighth inventor (given name, family name) \_\_\_\_\_

Inventor's Signature \_\_\_\_\_ Date \_\_\_\_\_

Residence \_\_\_\_\_ Citizenship \_\_\_\_\_

Post Office Address \_\_\_\_\_